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# SN54LVTH16240, SN74LVTH16240 3.3-V ABT 16-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

SCBS684D-MARCH 1997-REVISED DECEMBER 2006

#### **FEATURES**

- Members of the Texas Instruments Widebus™
   Family
- State-of-the-Art Advanced BiCMOS
   Technology (ABT) Design for 3.3-V Operation and Low Static-Power Dissipation
- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V<sub>CC</sub>)
- Support Unregulated Battery Operation Down to 2.7 V
- Typical V<sub>OLP</sub> (Output Ground Bounce) <0.8 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- I<sub>off</sub> and Power-Up 3-State Support Hot Insertion
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Distributed V<sub>CC</sub> and GND Pin Configuration Minimizes High-Speed Switching Noise
- Flow-Through Architecture Optimizes PCB Layout
- Latch-Up Performance Exceeds 500 mA Per JESD 17
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Package Options Include Plastic Shrink Small-Outline (DL) and Thin Shrink Small-Outline (DGG) Packages and 380-mil Fine-Pitch Ceramic Flat (WD) Package Using 25-mil Center-to-Center Spacings

SN54LVTH16240 . . . WD PACKAGE SN74LVTH16240 . . . DGG OR DL PACKAGE (TOP VIEW)

1 <del>OE</del>	1	48 20E	
1Y1	2	47 🛚 1A1	
1Y2 [	3	46 ] 1A2	
GND [	4	45 GND	
1Y3 [	5	44 🛚 1A3	
1Y4 [	6	43 🛚 1A4	
V <sub>cc</sub> [	7	42] V <sub>cc</sub>	
2Y1[	8	41 2A1	
2Y2 [	9	40 2A2	
GND [	10	39 GND	
2Y3 [	11	38 ] 2A3	
2Y4 [	12	37 🛚 2A4	
3Y1	13	36 ] 3A1	
3Y2 [	14	35 ] 3A2	
GND [	15	34 GND	
3Y3 [	16	33 ] 3A3	
3Y4 [	17	32 ] 3A4	
V <sub>cc</sub> [	18	31 V <sub>cc</sub>	
4Y1[	19	30 ] 4A1	
4Y2 [	20	29 ] 4A2	
GND [	21	28 GND	
4Y3 [	22	27 ] 4A3	
4Y4 [	23	26 ] 4A4	
4 <del>0E</del> [	24	25 3OE	
	ı		

#### **DESCRIPTION/ORDERING INFORMATION**

These 16-bit buffers/drivers are designed specifically for low-voltage (3.3-V)  $V_{CC}$  operation, but with the capability to provide a TTL interface to a 5-V system environment.

The 'LVTH16240 devices are designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

#### ORDERING INFORMATION

T <sub>A</sub>	PACKA	GE <sup>(1)</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING		
		Reel of 1000	SN74LVTH16240DLR			
	SSOP – DL	Reel of 1000	SN74LVTH16240DLRG4	1.7/1146240		
-40°C to 85°C	330P - DL	Tube of 25	SN74LVTH16240DL	LVTH16240		
-40°C to 85°C		Tube of 25	SN74LVTH16240DLG4			
	TSSOP – DGG	Reel of 2000	74LVTH16240DGGRE4	LVTH16240		
	1330P – DGG	Reel of 2000	SN74LVTH16240DGGR	LV1H16240		

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

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# **DESCRIPTION/ORDERING INFORMATION (CONTINUED)**

The devices can be used as four 4-bit buffers, two 8-bit buffers, or one 16-bit buffer. The devices provide inverting outputs and symmetrical active-low output-enable  $(\overline{OE})$  inputs.

When  $V_{CC}$  is between 0 and 1.5 V, the devices are in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

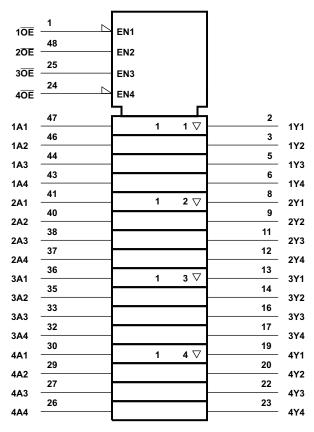
These devices are fully specified for hot-insertion applications using  $I_{off}$  and power-up 3-state. The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

The SN54LVTH16240 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74LVTH16240 is characterized for operation from –40°C to 85°C.

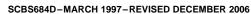
# FUNCTION TABLE (each 4-bit buffer)

INP	INPUTS						
ŌĒ	<del>OE</del> A						
L	Н	L					
L	L	Н					
Н	Χ	Z					

#### LOGIC SYMBOL(1)

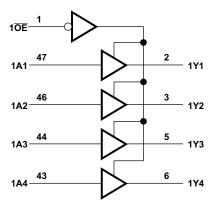


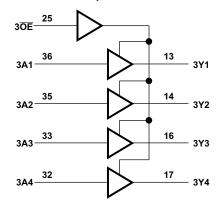
<sup>&</sup>lt;sup>(1)</sup>This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

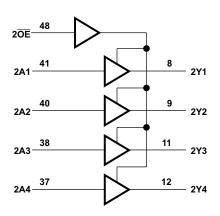


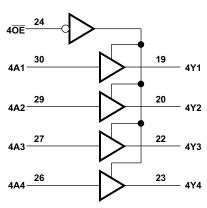


## **LOGIC DIAGRAM (POSITIVE LOGIC)**









# SN54LVTH16240, SN74LVTH16240 3.3-V ABT 16-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

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### Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT	
$V_{CC}$	Supply voltage range		-0.5	4.6	V	
$V_{I}$	Input voltage range (2)		-0.5	7	V	
Vo	Voltage range applied to any output in the high	oltage range applied to any output in the high-impedance or power-off state <sup>(2)</sup>				
Vo	Voltage range applied to any output in the high	-0.5	V <sub>CC</sub> + 0.5	V		
	Current into any output in the law state	SN54LVTH16240		96	mA	
I <sub>O</sub>	Current into any output in the low state	SN74LVTH16240		128	ША	
	Current into any output in the high state (3)	SN54LVTH16240		48	mA	
I <sub>O</sub>	Current into any output in the high state (3)	SN74LVTH16240		64		
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		-50	mA	
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA	
0	Dealtogo thermal impedance (4)	DGG package		89		
$\theta_{JA}$	Package thermal impedance (4)	DL package		94	°C/W	
T <sub>stg</sub>	Storage temperature range	Storage temperature range				

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

# **Recommended Operating Conditions**(1)

			SN54LVTH	SN54LVTH16240         SN74LVTH16240           MIN         MAX         MIN         MAX		116240	UNIT
			MIN			ONIT	
V <sub>CC</sub>	Supply voltage		2.7	3.6	2.7	3.6	V
V <sub>IH</sub>	High-level input voltage		2		2		V
V <sub>IL</sub>	Low-level input voltage		0.8		0.8	V	
$V_{I}$	Input voltage		5.5		5.5	V	
I <sub>OH</sub>	High-level output current			-24		-32	mA
I <sub>OL</sub>	Low-level output current			48		64	mA
Δt/Δν	Input transition rise or fall rate	Outputs enabled		10		10	ns/V
$\Delta t/\Delta V_{CC}$	Power-up ramp rate		200		200		μs/V
T <sub>A</sub>	Operating free-air temperature		<b>–</b> 55	125	-40	85	°C

<sup>(1)</sup> All unused control inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

 <sup>(2)</sup> The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
 (3) This current flows only when the output is in the high state and V<sub>O</sub> > V<sub>CC</sub>.
 (4) The package thermal impedance is calculated in accordance with JESD 51.



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#### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST OF	MDITIONS	SN54	LVTH16240	SN74I	LVTH1624	10	UNIT
PA	ARAMETER	IESI CC	ONDITIONS	MIN	TYP <sup>(1)</sup> MAX	MIN	TYP <sup>(1)</sup>	MAX	UNII
V <sub>IK</sub>		V <sub>CC</sub> = 2.7 V,	I <sub>I</sub> = -18 mA		-1.2			-1.2	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V},$	$I_{OH} = -100  \mu A$	V <sub>CC</sub> - 0.2		V <sub>CC</sub> - 0.2			
V		V <sub>CC</sub> = 2.7 V,	$I_{OH} = -8 \text{ mA}$	2.4		2.4			V
$V_{OH}$		V 2.V	I <sub>OH</sub> = -24 mA	2					V
		V <sub>CC</sub> = 3 V	$I_{OH} = -32 \text{ mA}$			2			
		V 0.7.V	I <sub>OL</sub> = 100 μA		0.2			0.2	
		V <sub>CC</sub> = 2.7 V	I <sub>OL</sub> = 24 mA		0.5			0.5	
.,			I <sub>OL</sub> = 16 mA		0.4			0.4	.,
$V_{OL}$			I <sub>OL</sub> = 32 mA		0.5			0.5	V
	$V_{CC} = 3 V$	I <sub>OL</sub> = 48 mA		0.55					
			I <sub>OL</sub> = 64 mA					0.55	
		$V_{CC} = 0 \text{ or } 3.6 \text{ V},$	V <sub>I</sub> = 5.5 V		10			10	
	Control inputs	$V_{CC} = 3.6 \text{ V},$	$V_I = V_{CC}$ or GND	±1					
կ	Data inputs	V 26V	$V_I = V_{CC}$		1			1	μА
	Data inputs	V <sub>CC</sub> = 3.6 V	V <sub>I</sub> = 0		-5			-5	
I <sub>off</sub>		$V_{CC} = 0$ ,	$V_{I}$ or $V_{O} = 0$ to 4.5 V					±100	μΑ
		V <sub>CC</sub> = 3 V	V <sub>I</sub> = 0.8 V	75		75			
I <sub>I(hold)</sub>	Data inputs	v <sub>CC</sub> = 3 v	V <sub>I</sub> = 2 V	-75		-75			μA
·I(noia)	Data inputo	$V_{CC} = 3.6 V^{(2)},$	$V_1 = 0 \text{ to } 3.6 \text{ V}$					500 -750	μι
I <sub>OZH</sub>		V <sub>CC</sub> = 3.6 V,	V <sub>O</sub> = 3 V		5			5	μΑ
I <sub>OZL</sub>		$V_{CC} = 3.6 \text{ V},$	V <sub>O</sub> = 0.5 V		-5			-5	μΑ
I <sub>OZPU</sub>		$\frac{V_{CC}}{OE}$ = 0 to 1.5 V, $V_{O}$ = $\frac{V_{CC}}{OE}$ = don't care	0.5 V to 3 V,		±100 <sup>(3)</sup>			±100	μΑ
I <sub>OZPD</sub>		$\frac{V_{CC}}{OE}$ = 1.5 V to 0, $V_{O}$ = $\frac{V_{CC}}{OE}$ = don't care	0.5 V to 3 V,		±100 <sup>(3)</sup>			±100	μА
		V <sub>CC</sub> = 3.6 V,	Outputs high		0.19			0.19	
$I_{CC}$		$I_{\Omega} = 0$ ,	Outputs low		5			5	mA
		$V_I = V_{CC}$ or GND	Outputs disabled		0.19			0.19	
ΔI <sub>CC</sub> <sup>(4)</sup>		$V_{CC} = 3 \text{ V to } 3.6 \text{ V, One}$ Other inputs at $V_{CC}$ or $0$			0.2			0.2	mA
Ci		V <sub>I</sub> = 3 V or 0			4		4		pF
Co		V <sub>O</sub> = 3 V or 0			9		9		pF

<sup>(1)</sup> All typical values are at  $V_{CC} = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ . (2) This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

On products compliant to MIL-PRF-38535, this parameter is not production tested.

<sup>(4)</sup> This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V<sub>CC</sub> or GND.

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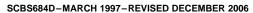


### **Switching Characteristics**

over recommended operating free-air temperature range,  $C_L = 50 \text{ pF}$  (unless otherwise noted) (see Figure 1)

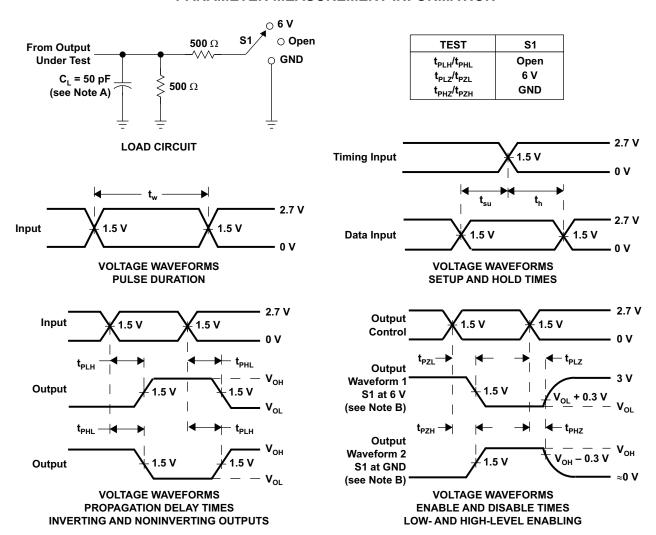
			SI	N54LVTH	116240										
PARAMETER	FROM (INPUT)	TO (OUTPUT)		V <sub>CC</sub> = 3.3 V ±0.3 V		V <sub>CC</sub> = 2.7 V		V <sub>CC</sub> = 3.3 V ±0.3 V			V <sub>CC</sub> = 2.7 V				
			MIN	MAX	MIN	MAX	MIN	TYP <sup>(1)</sup>	MAX	MIN	MAX				
t <sub>PLH</sub>	А	Υ	1	3.6		4.1	1	2.2	3.5		4	20			
t <sub>PHL</sub>	ζ	1	1	3.6		4.1	1	2.7	3.5		4	ns			
t <sub>PZH</sub>	ŌĒ	<b>V</b>	1	4.2		5.1	1	2.6	4		4.9	nc			
t <sub>PZL</sub>	OL	'	1.1	4.6		4.8	1.2	2.6	4.4		4.6	ns			
t <sub>PHZ</sub>	ŌĒ	Υ	1.9	4.7		5.2	2	3.4	4.5		5	20			
t <sub>PLZ</sub>	OE	Y	Y	Y	Y	1.9	4.4		4.5	2	3.2	4.2		4.2	ns
t <sub>sk(LH)</sub>									0.5		0.5	20			
t <sub>sk(HL)</sub>									0.5		0.5	ns			

<sup>(1)</sup> All typical values are at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C.





#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. C<sub>i</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_r \leq$  2.5 ns,  $t_f \leq$  2.5 ns.
- D. The outputs are measured one at a time, with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms





10-Dec-2020

#### **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVTH16240DGGR	ACTIVE	TSSOP	DGG	48	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH16240	Samples
SN74LVTH16240DL	ACTIVE	SSOP	DL	48	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH16240	Samples
SN74LVTH16240DLG4	ACTIVE	SSOP	DL	48	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH16240	Samples
SN74LVTH16240DLR	ACTIVE	SSOP	DL	48	1000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH16240	Samples
SN74LVTH16240DLRG4	ACTIVE	SSOP	DL	48	1000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH16240	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



### PACKAGE OPTION ADDENDUM

10-Dec-2020

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# PACKAGE MATERIALS INFORMATION

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### TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVTH16240DGGR	TSSOP	DGG	48	2000	330.0	24.4	8.6	13.0	1.8	12.0	24.0	Q1
SN74LVTH16240DLR	SSOP	DL	48	1000	330.0	32.4	11.35	16.2	3.1	16.0	32.0	Q1

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#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVTH16240DGGR	TSSOP	DGG	48	2000	367.0	367.0	45.0
SN74LVTH16240DLR	SSOP	DL	48	1000	367.0	367.0	55.0



SMALL OUTLINE PACKAGE



### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
  4. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



### DGG (R-PDSO-G\*\*)

### PLASTIC SMALL-OUTLINE PACKAGE

#### **48 PINS SHOWN**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

# DL (R-PDSO-G48)

# PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

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